MCH3474

N-Channel Power MOSFET 30V, 4A, 50mΩ, Single MCPH3



http://onsemi.com

Features

- · Low ON-resistance
- 1.8V drive
- · Protection diode in

- · Ultrahigh speed switching
- · Halogen free compliance

Specifications

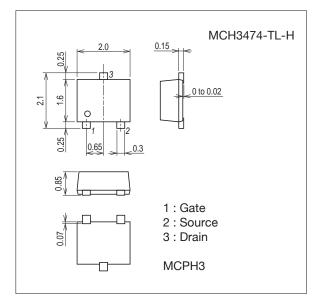
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		30	V
Gate-to-Source Voltage	VGSS		±12	V
Drain Current (DC)	ID		4	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	16	Α
Allowable Power Dissipation	PD	When mounted on ceramic substrate (900mm ² ×0.8mm)	1	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ) 7019A-003

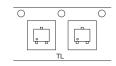


Product & Package Information

• Package : MCPH3

• JEITA, JEDEC : SC-70, SOT-323 • Minimum Packing Quantity : 3,000 pcs./reel

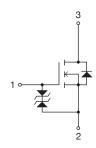
Packing Type: TL



Marking



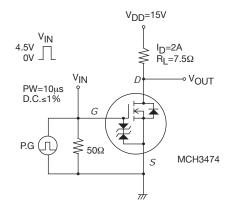
Electrical Connection



Electrical Characteristics at Ta=25°C

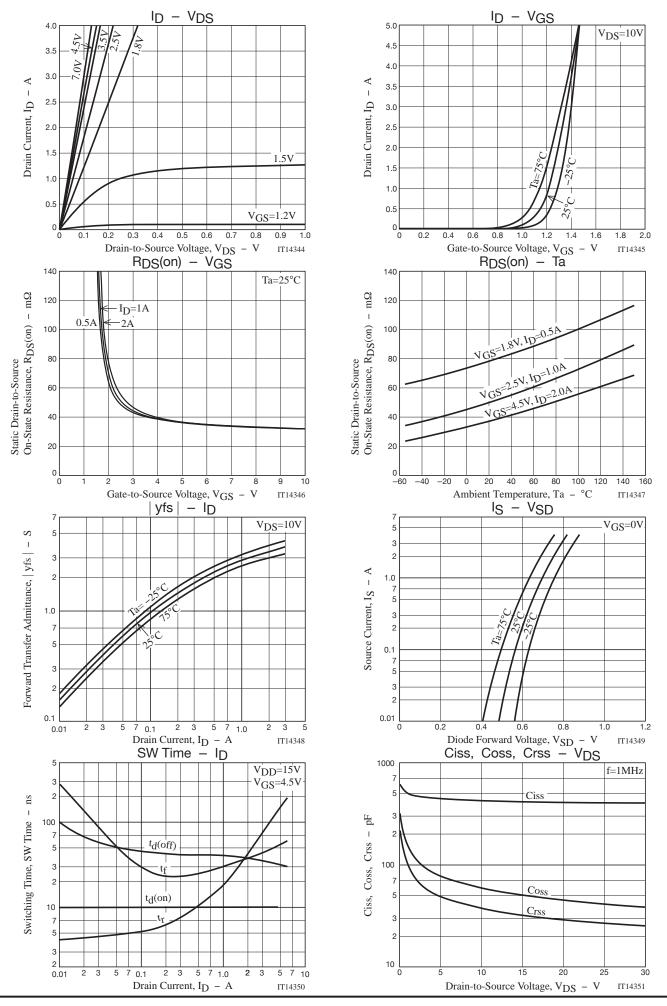
Parameter	Symbol	Conditions	Ratings			Unit	
Faranieter	Syllibol	Conditions	min	typ	max	Unit	
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	30			V	
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =30V, V _{GS} =0V			1	μΑ	
Gate-to-Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0V			±10	μΑ	
Cutoff Voltage	V _{GS} (off)	V _{DS} =10V, I _D =1mA	0.4		1.3	V	
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =2A	2.0	3.4		S	
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =2A, V _{GS} =4.5V		38	50	mΩ	
	R _{DS} (on)2	I _D =1A, V _G S=2.5V		51	72	mΩ	
	R _{DS} (on)3	I _D =0.5A, V _G S=1.8V		80	130	mΩ	
Input Capacitance	Ciss			430		рF	
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		59		рF	
Reverse Transfer Capacitance	Crss			38		рF	
Turn-ON Delay Time	t _d (on)			10		ns	
Rise Time	t _r	One are alified Took Observit		41		ns	
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		36		ns	
Fall Time	tf			37		ns	
Total Gate Charge	Qg			4.7		nC	
Gate-to-Source Charge	Qgs	V _{DS} =15V, V _{GS} =4.5V, I _D =4A		0.8		nC	
Gate-to-Drain "Miller" Charge	Qgd]		1.1		nC	
Diode Forward Voltage	V _{SD}	I _S =4A, V _{GS} =0V		0.82	1.2	V	

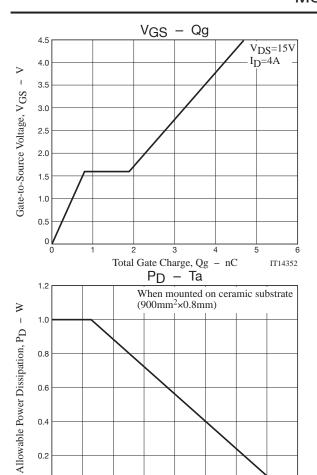
Switching Time Test Circuit



Ordering Information

Device	Package	Shipping	memo		
MCH3474-TL-H	MCPH3	3,000pcs./reel	Pb Free and Halogen Free		





ol

0

20

60

80

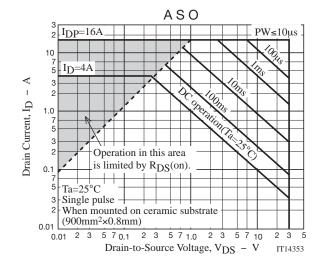
Ambient Temperature, Ta - °C

100

160

IT14354

140

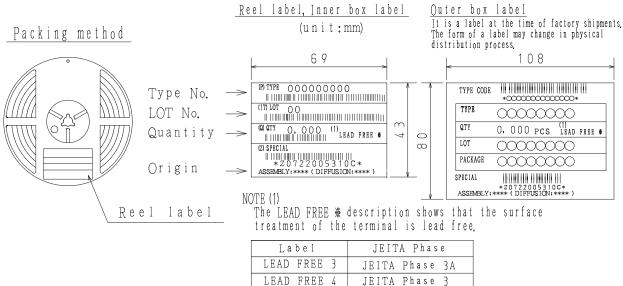


Taping Specification

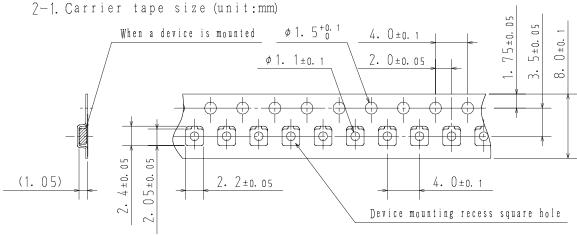
MCH3474-TL-H

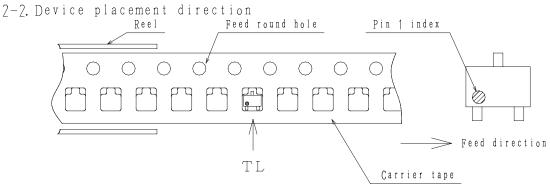
1. Packing Format

Package Name	Carrier Tape	Maximun Number of devices contained (pcs)			Packing	f o r m a t
	Туре	Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
мсрн3	мсрн3	3,000	15, 000	90,000	5 reels contained	6 inner boxes contained
					Dimensions:mm (external)	Dimensions:mm (external)
					183×72×185	440×195×210



2. Taping configuration

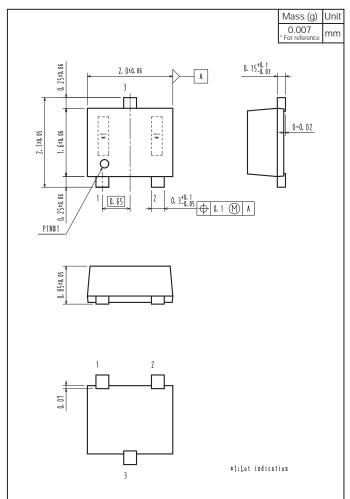




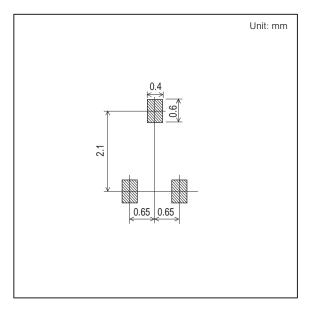
Those with pin 1 index on the feed hole side·····TL

Outline Drawing

MCH3474-TL-H



Land Pattern Example



Note on usage: Since the MCH3474 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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